
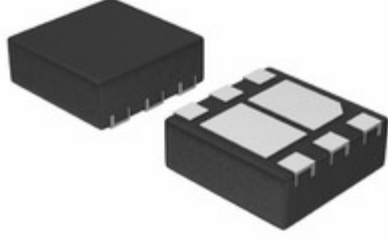



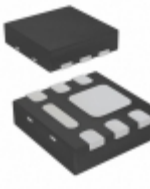






	<h2 style="color: red;">NVLJD4007N2TAG</h2>
	<p>Hersteller-Teilenummer: NVLJD4007N2TAG</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET 2N-CH 30V 0.245A WDFN6</p> <p>Datenblätter:  NVLJD4007N2TAG.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5898 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVLJD4007N2TAG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 30V 0.245A WDFN6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5898 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	755mW
Verpackung / Gehäuse	6-WDFN Exposed Pad
Supplier Device-Gehäuse	6-WDFN (2x2)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	245mA
Rds On (Max) @ Id, Vgs	7 Ohm @ 125mA, 4.5V
VGS (th) (Max) @ Id	1.5V @ 100µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	20pF @ 5V
Verpackung	Tape & Reel (TR)



















































NVLJD4007N2TAG ist neu im Original, Suche NVLJD4007N2TAG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVLJD4007N2TAG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVLJD4007N2TAG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>CMKDM8005 TR Central Semiconductor MOSFET 2P-CH 20V 0.65A SOT363</p>	 <p>NVLUS4C12N2TAG AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 10.7A 6UDFN</p>	 <p>IRF7307TRPBF International Rectifier (Infineon Technologies) MOSFET N/P-CH 20V 8-SOIC</p>	 <p>NX6020CAKSX Nexperia MOSFET N/P-CH TSSOP6</p>
 <p>AO8801L Alpha and Omega Semiconductor, Inc. MOSFET 2P-CH 20V 4.7 8TSSOP</p>	 <p>APTM100A40FT1G Microsemi MOSFET 2N-CH 1000V 21A SP1</p>	 <p>SQJ960EP-T1_GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 60V 8A</p>	 <p>FDMC7200S AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 30V 7A/13A POWER33</p>

heiße Teile

Mehr

 0805PC122KAT1A	 1206AC562KAT1A	 28F0121-1SR	 D 298D336X0010P2T	 2MBI100SK-060
 6MBI50N-060	 732776151	 D AEE04F36-L	 AM110P08-11B	 AT715-2.5KESR
 ATS276H-PG-B-C	 BA00AST-V5	 BCR08AS-12A-T14	 BH18LB1WHFV	 C0402CH1C180K020BC
 CC0402KRX7R9BB152	 CM400HB-90H	 CS4334-DSZ	 FGH60N60SF	 G3VM-401D
 KSD1221OTU	 LP2966IMM-2830	 LT024D105MAT2C	 LT6550CMS#TRPBF	 LTC3854IDDB#TRPBF
 M29F002BT120K1	 MCT5200.300	 MS04A05T2V2	 N25S818HAT21I	 P3500Q12ALRP
 P80C51SBB	 PEF24628EV1.1	 PS2561AL-1-V-F3	 PSB2132HV1.4	 QS3861SOX
 S-1721A2828-M6T1G	 SI3050-E-GTR	 SI7860DP-T1-GE3	 SM2403PSANC-TRG	 SMCJ150A-E3/57T
 SP060301M2U2X	 STC12LE5406AD	 T599F12EC	 TK11234BMCL	 TLE2141AIDRG4
 TPS73118DBVR	 TS925IDT	 UCC35705DG4	 VI-JNR-CX	 ZUW102412

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